

## Complete Dual-Band Quadrature Transmitters

## General Description

The MAX2361 dual-band, triple-mode complete transmitter for cellular phones represents an integrated and architecturally advanced solution for this application. The device takes a differential I/Q baseband input and converts it up to IF through a quadrature modulator and IF variable-gain amplifier (VGA). The signal is then routed to an external bandpass filter and upconverted to RF through an image-reject mixer and RF VGA. The signal is further amplified with an on-chip PA driver. An IF synthesizer, an RF synthesizer, a local oscillator (LO) buffer, and a 3-wire programmable bus complete the basic functional blocks of this IC. The MAX2363 supports single-band, sin-gle-mode (PCS) operation. The MAX2365 supports sin-gle-band cellular dual-mode operation.
The MAX2361 enables architectural flexibility because of its two IF voltage-controlled oscillators (VCOs), two IF ports, two RF LO input ports, and three PA driver output ports. The devices allow the use of a single receive IF frequency and split-band PCS filters for optimum out-ofband noise performance. The low-noise PA drivers allow up to three RF SAW filters to be eliminated. Select a mode of operation by loading data on the SPI ${ }^{T M} /$ QSPI ${ }^{\text {TM }} / \mathrm{MICROWIRE}{ }^{T M}$-compatible 3 -wire serial bus. Charge-pump current, IF/RF gain balancing, standby, shutdown plus additional functions, are also controlled with the serial interface.
The MAX2361/MAX2363/MAX2365 come in a 48-pin TQFN-EP and QFN-EP package and are specified for the extended $\left(-40^{\circ} \mathrm{C}\right.$ to $\left.+85^{\circ} \mathrm{C}\right)$ temperature range.

Applications
CDMA, cdma2000$, ~ T D M A, ~ W-C D M A, ~$ GAIT Mobile Phones
Satellite Phones
Wireless Data Links (WAN/LAN)
Wireless Local Area Networks (LANs) High-Speed Data Modems

Pin Configurations appear at end of data sheet.
Selector Guide appears at end of data sheet.
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- Dual-Band, Triple-Mode Operation
- +9dBm Linear Output Power
- 100dB Power-Control Range
- Supply Current Drops as Output Power is Reduced
- Dual Synthesizer for IF and RF LO
- Dual On-Chip IF VCO
- QSPI/SPI/MICROWIRE-Compatible 3-Wire Bus
- Digitally Controlled Operational Modes
- Single Sideband Upconverter Eliminates SAW Filters
- Directly Drives Power Amplifier

| PART | TEMP RANGE | PIN-PACKAGE |
| :--- | :--- | :--- |
| MAX2361EGM | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | 48 QFN-EP* |
| MAX2361ETM | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | 48 TQFN-EP |
| MAX2363EGM | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | 48 QFN-EP* |
| MAX2363ETM | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | 48 TQFN-EP ${ }^{*}$ |
| MAX2365EGM | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | 48 QFN-EP |
| MAX2365ETM | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | 48 TQFN-EP ${ }^{*}$ |

*EP = exposed paddle.
Features

## Ordering Information

Functional Diagram


## Complete Dual-Band Quadrature Transmitters

## ABSOLUTE MAXIMUM RATINGS

Vcc to GND


RFL, RFH0, RFH1,
VCCIFCP, VCCRFCP, VCCDRV to GND. $\qquad$
DI, CLK, CS, GC, SHDN, TXGATE,
IDLE, LOCK to GND ...............................-0.3V to (Vcc + 0.3V)
AC Input Pins (IFINL_, IFINH_, Q_ I_ TANKL_, TANKH,
REF, RFPLL, LOL, LOH). $\qquad$ .1.0V peak

Digital Input Current ( $\overline{\mathrm{SHDN}}, \overline{\text { TXGATE }}, \overline{\mathrm{IDLE}}$,
CLK, DI, $\overline{C S}$ ) .............................................................. $\pm 10 \mathrm{~mA}$
Continuous Power Dissipation ( $\mathrm{T}_{\mathrm{A}}=+70^{\circ} \mathrm{C}$ )
48-Pin QFN-EP (derate $27 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$ above $+70^{\circ} \mathrm{C}$ ) .............. 2.1 W
Operating Temperature Range ........................... $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$
Junction Temperature ..................................................... $+150^{\circ} \mathrm{C}$
Storage Temperature Range ............................. $65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$
Lead Temperature (soldering, 10s) ................................. $300^{\circ} \mathrm{C}$

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## DC ELECTRICAL CHARACTERISTICS

(MAX2361/MAX2363/MAX2365, $\overline{S H D N}=\overline{\mathrm{DLE}}=\overline{\text { TXGATE }}=$ high, $\mathrm{VGC}_{\mathrm{GC}}=2.4 \mathrm{~V}, \mathrm{R}_{\mathrm{BIAS}}=10 \mathrm{k} \Omega$, ICCCTRL is in power-up state, no AC signals applied, $\mathrm{V}_{\mathrm{CC}}=+2.7 \mathrm{~V}$ to $+3.3 \mathrm{~V}, \mathrm{~V}_{\mathrm{BAT}}=+2.7 \mathrm{~V}$ to $+4.5 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$, unless otherwise noted. Typical values are at $\mathrm{V}_{\mathrm{CC}}=\mathrm{V}_{\mathrm{BAT}}=+2.8 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$, and operating modes are defined in Table 9.)


## Complete Dual-Band Quadrature Transmitters

## ELECTRICAL CHARACTERISTICS

(MAX2361/MAX2363/MAX2365 EV kit, $50 \Omega$ system, operating modes as defined in Table 9, TEMP_COMP = 10, input voltage at I
 $\mathrm{V}_{\mathrm{BAT}}=\overline{\mathrm{SHDN}}=\overline{\mathrm{IDLE}}=\overline{\mathrm{CS}}=\overline{\mathrm{TXGATE}}=2.8 \mathrm{~V}, \mathrm{LOH}, \mathrm{LOL}$ input power $=-10 \mathrm{dBm}, \mathrm{f}_{\mathrm{LOL}}=966.38 \mathrm{MHz}, \mathrm{f}_{\mathrm{LOH}}=1750 \mathrm{MHz}, \mathrm{f}_{\mathrm{RFH}}=\mathrm{f}_{\mathrm{RFH}} 1$ $=1880.38 \mathrm{MHz}, \mathrm{f}_{\mathrm{RFL}}=836 \mathrm{MHz}, \mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$, unless otherwise noted.)


## Complete Dual-Band Quadrature Transmitters

## ELECTRICAL CHARACTERISTICS (continued)

(MAX2361/MAX2363/MAX2365 EV kit, $50 \Omega$ system, operating modes as defined in Table 9, TEMP_COMP = 10, input voltage at I
 $\mathrm{V}_{\mathrm{BAT}}=\overline{\mathrm{SHDN}}=\overline{\mathrm{IDLE}}=\overline{\mathrm{CS}}=\overline{\mathrm{TXGATE}}=2.8 \mathrm{~V}, \mathrm{LOH}, \mathrm{LOL}$ input power $=-10 \mathrm{dBm}, \mathrm{f}_{\mathrm{LOL}}=966.38 \mathrm{MHz}, \mathrm{f}_{\mathrm{LOH}}=1750 \mathrm{MHz}, \mathrm{f}_{\mathrm{RFH}}=\mathrm{f}_{\mathrm{RFH}} 1$ $=1880.38 \mathrm{MHz}, \mathrm{f}_{\mathrm{RFL}}=836 \mathrm{MHz}, \mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$, unless otherwise noted.)

| PARAMETER | CONDITIONS |  | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CASCADED MODULATOR, UPCONVERTER, AND PREDRIVER |  |  |  |  |  |  |
| RFL Output Power | $M P L=1, T_{A}=-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$, meets ACPR specifications (Note 1) |  | 6.8 | 9 |  | dBm |
| RFH0 Output Power | $\begin{aligned} & \mathrm{MPL}=1, \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C} \text { to }+85^{\circ} \mathrm{C} \text {, meets ACPR } \\ & \text { specifications (Note 1) } \end{aligned}$ |  | 7.7 | 10.7 |  | dBm |
| RFH1 Output Power | $\mathrm{MPL}=1, \mathrm{~T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$, meets ACPR specifications (Note 1) |  | 6.6 | 9.7 |  | dBm |
| RFL Adjacent Channel Power Ratio | foFFSET $= \pm 885 \mathrm{kHz}$ in 30 kHz bandwidth |  |  |  | -52 | dBc |
| RFL Alternate Channel Power Ratio | foFFSET $= \pm 1.98 \mathrm{MHz}$ in 30 kHz bandwidth |  |  |  | -65 | dBc |
| RFH_Adjacent Channel Power Ratio | foFFSET $= \pm 1.25 \mathrm{MHz}$ in 30 kHz bandwidth |  |  |  | -52 | dBc |
| RFH_Alternate Channel Power Ratio | foFFSET $= \pm 1.98 \mathrm{MHz}$ in 30 kHz bandwidth |  |  |  | -68 | dBc |
| RX Band Noise Power (Note 1) | $\mathrm{MPL}=1, \mathrm{PRFL}=+8 \mathrm{dBm}$ | Noise measured at +45 MHz offset |  | -131 | -128 | $\begin{gathered} \mathrm{dBm} / \\ \mathrm{Hz} \end{gathered}$ |
|  | $\mathrm{MPL}=0, \mathrm{PRFL}=+5 \mathrm{dBm}$ |  |  | -134 | -131 |  |
|  | $\mathrm{MPL}=1, \mathrm{P}_{\text {RFH_ }}=+8 \mathrm{dBm}$ | Noise measured at +80 MHz offset |  | -131 | -128 |  |
|  | $\mathrm{MPL}=0, \mathrm{P}_{\text {RFH }}=+5 \mathrm{dBm}$ |  |  | -133 | -130 |  |
| Output Power Variation Over Temperature | Relative to $+25^{\circ} \mathrm{C}, \mathrm{T}_{\mathrm{A}}=-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |  |  | $\pm 1$ |  | dB |
| IF_PLL |  |  |  |  |  |  |
| Reference Frequency |  |  | 5 |  | 30 | MHz |
| Reference Frequency Signal Level |  |  | 0.1 |  | 0.6 | VP-P |
| IF Main Divide Ratio |  |  | 256 |  | 16383 |  |
| IF Reference Divide Ratio |  |  | 2 |  | 2047 |  |
| VCO Operating Range | VCO_SEL $=0$ |  | 240-470 |  |  | MHz |
|  | VCO_SEL $=1$ |  | 240-760 |  |  |  |
| Charge-Pump Source/Sink Current | ICP $=00$ |  | 114 | 139 | 178 | $\mu \mathrm{A}$ |
|  | ICP $=01$ |  | 158 | 192 | 246 |  |
|  | ICP $=10$ |  | 228 | 278 | 356 |  |
|  | ICP $=11$ |  | 319 | 390 | 499 |  |

## Complete Dual-Band Quadrature Transmitters

## ELECTRICAL CHARACTERISTICS (continued)

(MAX2361/MAX2363/MAX2365 EV kit, $50 \Omega$ system, operating modes as defined in Table 9, TEMP_COMP = 10, input voltage at I and $\mathrm{Q}=600 \mathrm{~m} V_{\text {P_P }}$ differential, 300 kHz quadrature CW tones, RF and IF synthesizers locked, $\mathrm{V}_{\text {REF }}=200 \mathrm{mV} \mathrm{V}_{\text {P-P }}$ at $19.68 \mathrm{MHz}, \mathrm{V}_{\text {CC }}=$ $\mathrm{V}_{\mathrm{BAT}}=\overline{\mathrm{SHDN}}=\overline{\mathrm{IDLE}}=\overline{\mathrm{CS}}=\overline{\mathrm{TXGATE}}=2.8 \mathrm{~V}, \mathrm{LOH}, \mathrm{LOL}$ input power $=-10 \mathrm{dBm}, \mathrm{fLOL}=966.38 \mathrm{MHz}, \mathrm{f}$ LOH $=1750 \mathrm{MHz}, \mathrm{f}_{\mathrm{RFH}}=\mathrm{f}_{\mathrm{RFH}} 1$ $=1880.38 \mathrm{MHz}, \mathrm{fRFL}=836 \mathrm{MHz}, \mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$, unless otherwise noted.)

| PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Turbolock Boost Current | ICP_MAX = 1 | 632 | 774 | 987 | $\mu \mathrm{A}$ |
| Charge-Pump Source/Sink Matching | All values of ICP, over specified compliance range |  |  | 6 | \% |
| IF Charge-Pump Compliance |  | 0.5 |  | $\mathrm{V}_{\mathrm{CCIFCP}}$ | V |
| Charge-Pump High-Z Leakage | Over specified compliance range |  | 20 |  | pA |
| RF_PLL |  |  |  |  |  |
| Reference Frequency |  | 5 |  | 30 | MHz |
| RF Main Divide Ratio |  | 4096 |  | 262143 |  |
| RF Reference Divide Ratio |  | 2 |  | 8191 |  |
| Charge-Pump Source/Sink Current | $\mathrm{RCP}=00$ | 266 | 325 | 416 | $\mu \mathrm{A}$ |
|  | $\mathrm{RCP}=01$ | 533 | 650 | 832 |  |
|  | $\mathrm{RCP}=10$ | 605 | 738 | 945 |  |
|  | $\mathrm{RCP}=11$ | 872 | 1063 | 1361 |  |
| Turbolock Boost Current | (Note 5) | 1388 | 1694 | 2168 | $\mu \mathrm{A}$ |
| Charge-Pump Source/Sink Matching | All values of RCP, over specified compliance range |  |  | 6 | \% |
| RF Charge Pump Compliance |  | 0.5 |  | $\begin{gathered} \text { VCCRFCP } \\ -0.5 \end{gathered}$ | V |
| Phase Detector Noise Floor | $R C P=11$, RCP_TURBO1 $=$ RCP_TURBO2 $=0$, 30 kHz comparison frequency |  | -162 |  | dBc/Hz |
| Charge-Pump High-Z Leakage | Over specified compliance range |  | 20 |  | pA |
| RFPLL Input Sensitivity |  | 160 |  |  | MVP-P |

Note 1: Guaranteed by design and characterization to 3 sigma (includes board and component variations).
Note 2: ACPR is met over the specified $\mathrm{V}_{\text {CM }}$ range.
Note 3: $V_{C M}$ must be supplied by the I/Q baseband source with $\pm 8 \mu \mathrm{~A}$ capability.
Note 4: IQ_LEVEL $=0, V_{Q}=V_{L_{-}}=87 \mathrm{~m} V_{R M S}$ differential, IS98 reverse channel modulation at $415 \mathrm{mVp}-\mathrm{p}$ differential with $0.1 \% 4.5 \mathrm{~dB}$ peak-to-average ratio.
Note 5: When enabled with RCP_TURBO1 and RCP_TURBO2 (see Tables 2 and 3), the total charge-pump current is specified. For all values of RCP, the total turbolock current is 1.63 times the corresponding nonturbo current value.

## Complete Dual-Band

 Quadrature TransmittersTypical Operating Characteristics
(MAX2361 EV kit, $\mathrm{V}_{\mathrm{CC}}=\mathrm{V}_{\mathrm{BAT}}=+2.8 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$, unless otherwise noted.)


SUPPLY CURRENT vs. VGC


RF IMAGE REJECTION FROM IRNL


IF IMACE REJECTION


RF IMACE REJECTION FROM IFNH


## Complete Dual-Band Quadrature Transmitters

Typical Operating Characteristics (continued)
(MAX2361 EV kit, $\mathrm{V}_{\mathrm{CC}}=\mathrm{V}_{\mathrm{BAT}}=+2.8 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$, unless otherwise noted.)


IF OUIPUT POWER vs. Vac



IF OUTPUT PONER vs. VGC


IF POWER vs. IFGSEITING


CASCADED ACPR AND ALTR vs. ICCPA (RFHD)


## Complete Dual-Band Quadrature Transmitters

## Typical Operating Characteristics (continued)

(MAX2361 EV kit, $\mathrm{V}_{\mathrm{CC}}=\mathrm{V}_{\mathrm{BAT}}=+2.8 \mathrm{~V}, \mathrm{~T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$, unless otherwise noted.)



IF PレLOCKTIME


ICP = 11, ICP MAX = 0
$\mathrm{f}_{\mathrm{COMP}}=240 \mathrm{kHz}, \mathrm{f}_{\mathrm{IF}}=263.64 \mathrm{MHz}$
LOOP FILTER: 20k $\Omega$ IN SERIES WITH 2.2nF, 220pF PARALLEL LOOP BW = 10kHz

LOHPORT $\mathrm{S}_{1}$


RFPL PORT $\mathrm{S}_{1}$


## Complete Dual-Band Quadrature Transmitters

| Pin Description |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
| PIN |  |  | NAME | FUNCTION |
| MAX2361 | MAX2363 | MAX2365 |  |  |
| 1 | - | 1 | RFL | Transmitter RF Output for Cellular Band ( 800 MHz to 1000 MHz )—for both FM and digital modes. This open-collector output requires a pullup inductor to the supply voltage, which may be part of the output matching network and can be connected directly to the battery. |
| 2 | 2 | - | RFH0 | Transmitter RF Output for PCS Band (1700MHz to 2000MHz). This opencollector output requires a pullup inductor to the supply voltage. The pullup inductor may be part of the output matching network and may be connected directly to the battery. For split band PCS application, use RFH0 for the 1880MHz-1910MHz range. |
| 3 | 3 | 3 | LOCK | Open-Collector Output Indicating Lock Status of the IF and/or the RF PLLs. Requires a pullup resistor. Control using configuration register bits LD_MODE. |
| 4 | 4 | 4 | VCCDRV | Supply Pin for the Driver Stage. May be connected directly to the battery. Bypass to PC board ground as close to the pin as possible. The ground vias for the bypass capacitor should not be shared by any other branch. |
| 5 | 5 | 5 | $\overline{\text { IDLE }}$ | Digital Input, Drive to Logic High for Normal Operation. A logic low on $\overline{\mathrm{IDLE}}$ shuts down everything except the RF PLL and associated registers. A small R-C lowpass can be used to filter digital noise. |
| 6 | 6 | 6 | VCC | Supply Pin for the Upconverter Stage. VCC must be bypassed to system ground as close to the pin as possible. The ground vias for the bypass capacitor should not be shared by any other branch. |
| 7 | 7 | 7 | TXGATE | Digital Input, Drive to Logic High for Normal Operation. A logic low on TXGATE shuts down everything except the RF PLL, IF PLL, IF VCO, and serial bus and registers. This mode is used for gated transmission. |
| 8, 9 | - | 8, 9 | IFINL+, IFINL- | Differential Inputs to the RF Upconverter. These pins are internally biased. The input impedance for these ports is nominally $400 \Omega$ differential. The IF filter should be AC-coupled to these ports. Keep the differential lines as short as possible to minimize stray pickup and shunt capacitance. |
| 10, 11 | 10, 11 | - | IFINH+, IFINH- | Differential Inputs to the RF Upconverter. These pins are internally biased. The input impedance for these ports is nominally $400 \Omega$ differential. The IF filter should be AC-coupled to these ports. Keep the differential lines as short as possible to minimize stray pickup and shunt capacitance. |
| 12 | 12 | 12 | BIAS | Bias Resistor Pin. BIAS is internally biased to approximately 600 mV . An external resistor between this pin to GND sets the bias current for the upconverters and PA driver stages. The nominal resistor value is $10 \mathrm{k} \Omega$. This value can be altered to optimize the linearity of the driver stage. |
| 13, 14, 15 | 13, 14, 15 | 13, 14, 15 | $\frac{\mathrm{CLK}, \mathrm{DI}}{\overline{\mathrm{CS}}}$ | Input Pins from the 3-Wire Serial Bus (SPI/QSPI/MICROWIRE compatible) |

## Complete Dual-Band

 Quadrature Transmitters| PIN |  |  | NAME | FUNCTION |
| :---: | :---: | :---: | :---: | :---: |
| MAX2361 | MAX2363 | MAX2365 |  |  |
| 16, 17 | 16, 17 | - | IFOUTH-, IFOUTH+ | Differential IF Outputs. These ports are active when the register bit IF_SEL is 1. They do not support FM mode. These pins must be inductively pulled up to $\mathrm{V}_{\mathrm{CC}}$. A differential IF bandpass filter is connected between this port and IFINH+ or IFINH-. The pullup inductors can be part of the filter structure. The differential output impedance of this port is nominally $600 \Omega$. The transmission lines from these pins should be short to minimize the pickup of spurious signals and noise. |
| 18, 19 | - | 18, 19 | IFOUTL-, IFOUTL+ | Differential IF Outputs. These ports are active when the register bit IF_SEL is 0 . These pins must be inductively pulled up to $\mathrm{V}_{\mathrm{CC}}$. A differential IF bandpass filter is connected between this port and IFINL+ and IFINL-. The pullup inductors can be part of the filter structure. The differential output impedance of this port is nominally $600 \Omega$. The transmission lines from these pins should be short to minimize the pickup of spurious signals and noise. |
| 20 | 20 | 20 | GC | RF and IF Gain Control Analog Input. Apply 0.6 V to 2.4 V to control the gain of the RF and IF stages. An RC filter on this pin should be used to reduce DAC noise or PDM clock spurs from this line. |
| 21 | 21 | 21 | VCC | Supply Pin for the IF VGA. Bypass with a capacitor as close to the pin as possible. The bypass capacitor must not share its ground vias with any other branches. |
| 22 | 22 | 22 | VCC | Supply for the I/Q Modulator. Bypass with a capacitor as close to the pin as possible. The bypass capacitor must not share its ground vias with any other branches. |
| 23, 24 | 23, 24 | 23, 24 | Q+, Q- | Differential Q-Channel Baseband Inputs to the Modulator. These pins go directly to the bases of a differential pair and require an external commonmode bias voltage. |
| 25, 26 | 25, 26 | 25, 26 | I+, I- | Differential I-Channel Baseband Inputs to the Modulator. These pins go directly to the bases of a differential pair and require an external commonmode bias voltage. |
| 27 | 27 | 27 | $\overline{\text { SHDN }}$ | Shutdown Input, Drive to Logic High for Normal Operation. A logic low on SHDN shuts down the entire IC except the serial interface and retains the information in all registers. An R-C lowpass can be used to filter digital noise. |
| 28 | 28 | 28 | VCC | Supply Pin to the VCO Section. Bypass as close to the pin as possible. The bypass capacitor should not share its vias with any other branches. |
| 29 | 29 | 29 | IFLO | Buffered LO Output. Control the output buffer using register bit BUF_EN and the divide ratio using the register bit BUF_DIV. |
| 30, 31 | - | 30, 31 | TANKL-, TANKL+ | Differential Tank Pins for the Low-Frequency IF VCO. These pins are internally biased. VCO_SEL $=0$ selects this IF VCO. |

## Complete Dual-Band Quadrature Transmitters

Pin Description (continued)

| PIN |  | NAME | FUNCTION |
| :---: | :---: | :---: | :---: | :--- |

# Complete Dual-Band Quadrature Transmitters 


#### Abstract

Detailed Description The MAX2361 complete quadrature transmitter accepts differential I/Q baseband inputs with external commonmode bias. A modulator upconverts this to IF frequency in the 120 MHz to 380 MHz range. A gain-control voltage pin (GC) controls the gain of both the IF and RF VGAs simultaneously to achieve the best current consumption and linearity performance. The IF signal is brought offchip for filtering, then fed to a single sideband upconverter followed by the RF VGA and PA driver. The RF upconverter requires an external VCO for operation. The IF PLL, RF PLL, and operating mode can be programmed by an SPI/QSPI/MICROWIRE-compatible 3wire interface. The following sections describe each block in the MAX2361 Functional Diagram.


I/Q Modulator
Differential in-phase (I) and quadrature-phase (Q) input pins are designed to be DC-coupled and biased with the baseband output from a digital-to-analog converter (DAC). I and Q inputs need a DC bias of $\mathrm{V}_{\mathrm{cc}} / 2$ and a current-drive capability of $8 \mu \mathrm{~A}$. The I and Q inputs capacitance is typically 0.3 pF differential. Commonmode voltage works within a 1.35 V to (VCC -1.25 V ) range. The IF VCO output is fed into a divide-bytwo/quadrature generator block to derive quadrature LO components to drive the IQ modulator. The output of the modulator is fed into the VGA.

## IF VCOs

There are two VCOs to support high IF and low IF frequencies. The VCOs oscillate at twice the desired IF frequency. Oscillation frequency is determined by external tank components (see Applications Information). Typical phase-noise performance for the tank is as shown in the Typical Operating Characteristics. The high-band and low-band VCOs can be selected independently of the IF port being used.

## IFLO Output Buffer

 IFLO provides a buffered LO output when BUF_EN is 1. The IFLO output frequency is equal to the VCO frequency when BUF_DIV is 0 , and half the VCO frequency when BUF_DIV is 1 . The output power is -12 dBm . This output is intended for applications where the receive IF is the same frequency as the transmit IF.IF/RF PLL
The IF/RF PLL uses a charge-pump output to drive a loop filter. The loop filter typically is passive secondorder lead lag filter. Outside the filter's bandwidth, phase noise is determined by the tank components. The two components that contribute most significantly to phase noise are the inductor and varactor. Use high$Q$ inductors and varactors to maximize equivalent parallel resistance. The IF_TURBO_CHARGE, RCP_TURBO1, and RCP_TURBO2 bits can be set to enable turbo mode. Turbo mode provides maximum charge-pump current during frequency acquisition. Turbo mode is disabled after frequency acquisition is achieved. When turbo mode is disabled, charge-pump current returns to the programmed levels as set by ICP and RCP bits in the CONFIG register (Table 3).
The PSS bit selects the RFPLL prescaler speed independent of the MODE bits. This enables PCS band VCO locking when transmitting in the cellular band. For VCO frequency above 1300 MHz , set PSS to 1 .

IF VGA
The IF VGA allows varying an IF output level that is controlled by GC voltage. The voltage range on GC of 0.6 V to 2.4 V provides a gain-control range of 85 dB . There are two differential IF output ports from the VGA. IFOUTL+/IFOUTL- are optimized for low IF operation ( 120 MHz to 235 MHz ); IFOUTH+/IFOUTH- support high IF operation ( 120 MHz to 380 MHz ). IFOUTL supports FM mode by providing higher IF output level when MODE is set to 00 .

Single Sideband Mixer The RF transmit mixer uses a single sideband architecture to eliminate an off-chip RF filter. The single sideband mixer has IF input stages that correspond to IF output ports of the VGA. The mixer is followed by the RF VGA. The RF VGA is controlled by the same GC pin as the IF VGA to provide optimum current consumption and linearity performance. The total power-control range is $>100 \mathrm{~dB}$.

PA Driver
The MAX2361 includes three power-amplifier (PA) drivers. Each is optimized for the desired operating frequency. RFL is optimized for cellular-band operation. RFH0 and RFH1 are optimized for split-band PCS operation. Use RFHO in single high-band output such as TDMA or W-CDMA. The PA drivers have open-collector outputs and require pullup inductors. The pullup inductors can act as the shunt element in a shunt series match.

## Complete Dual-Band Quadrature Transmitters

## Programmable Registers

The MAX2361/MAX2363/MAX2365 include eight programmable registers consisting of four divide registers, a configuration register, an operational control register, a current control register, and a test register. Each register consists of 24 bits. The 4 least significant bits (LSBs) are the register's address. The 20 most significant bits (MSBs) are used for register data. All registers contain some "don't care" bits. These can be either a " 0 " or a " 1 " and will not affect operation (Figure 1). Data is shifted in MSB first, followed by the 4-bit address. When $\overline{\mathrm{CS}}$ is low, the clock is active and data is shifted with the rising edge of the clock. When $\overline{\mathrm{CS}}$ transitions to high, the shift register is latched into the register selected by the contents of the address bits. Power-up defaults for the eight registers are shown in Table 1. The dividers and control registers are programmed from the SPI/QSPI/MICROWIRE-compatible serial port.
The RFM register sets the main frequency divide ratio for the RF PLL. The RFR register sets the reference frequency divide ratio. The RF VCO frequency can be determined by the following:

$$
\text { RF VCO frequency }=\mathrm{fREF} \times(\mathrm{RFM} / \mathrm{RFR})
$$

IFM and IFR registers are similar:

$$
\text { IF VCO frequency }=\text { fREF } \times(\text { IFM } / \text { IFR })
$$

where fREF is the external reference frequency.
The operational control register (OPCTRL) controls the state of the MAX2361/MAX2363/MAX2365. See Table 2 for the function of each bit.
The configuration register (CONFIG) sets the configuration for the RF/IF PLL and the baseband I/Q input levels. See Table 3 for a description of each bit.
The current control register modifies the bias current to accommodate different operation modes. In the highpower mode, MPL $=1$ sets the bias current and conversion gain to deliver a minimum of +8 dBm output
power from the PA drivers. In the low-power mode, MPL $=0$ sets the bias current and conversion gain to deliver a minimum of +5 dBm output power from the PA drivers. I_MULT sets the current multiplication factor for the PA driver stages according to Table 5. THROTTLE_BACK sets the rate of bias current changes when the output power changes according to Table 6. For example, when THROTTLE_BACK = 011 (default), the PA driver bias current reduces by 1dBmA for every 1 dB reduction in output power. THROTTLE_BACK = 000 setting gives a more aggressive current reduction (1.3dBmA/dB power) at the expense of linearity. THROTTLE_BACK setting does not affect the bias current at maximum power level.
The test register has to be 100hex for normal operation. The best way to ensure this is to program the test regiser to 100hex.

## Power Management

 Bias control is distributed among several functional sections and can be controlled to accommodate many different power-down modes as shown in Table 8.The serial interface remains active during shutdown. Setting SHDN_BIT $=0$ or $\overline{\text { SHDN }}=$ GND powers down the device. In either case, PLL programming and register information is retained.

Signal Flow Control Table 9 shows an example of key registers for triplemode operation, assuming half-band PCS and IF frequencies of $228.6 \mathrm{MHz} / 263.6 \mathrm{MHz}$.

## Applications Information

The MAX2361 is designed for use in dual-band, triplemode systems. It is recommended for triple-mode handsets (Figure 2). The MAX2363 is designed for use in CDMA PCS handset or W-CDMA systems (Figure 3). The MAX2365 is designed for use in dual-mode cellular systems (Figure 4).

## Table 1. Register Power-Up Default States

| REGISTER | DEFAULT | ADDRESS |  |
| :---: | :---: | :---: | :--- |
| RFM | 32214 dec | $0000_{\mathrm{b}}$ | RF M divider count |
| RFR | 656 dec | $0001_{\mathrm{b}}$ | RF R divider count |
| IFM | 6519 dec | $0010_{\mathrm{b}}$ | IF M divider count |
| IFR | 0492 dec | $0011_{\mathrm{b}}$ | IF R divider count |
| OPCTRL | 090 F hex | $0100_{\mathrm{b}}$ | Operational control settings |
| CONFIG | D03F hex | $0101_{\mathrm{b}}$ | Configuration and setup control |
| ICCCTRL | 0038 hex | $0110_{\mathrm{b}}$ | Current multiplication factor, PLL band |
| TEST | 100 hex | $0111_{\mathrm{b}}$ | Test-mode control |

## Complete Dual-Band

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Figure 1. Register Configuration

Cascaded Performance
Tables 11 and 12 show the typical cascaded performance for TDMA and W-CDMA systems.

## 3-Wire Interface

Figure 5 shows the 3 -wire interface timing diagram. The 3 -wire bus is SPI/QSPI/MICROWIRE compatible.

## Electromagnetic

Compliance Considerations
Two major concepts should be employed to produce a low-spur and EMC-compliant transmitter: minimize circular current-loop area to reduce H -field radiation. To minimize circular current-loop area, bypass as close to
the part as possible and use the distributed capacitance of a ground plane. To minimize voltage drops, make $\mathrm{V}_{\mathrm{CC}}$ traces short and wide, and make RF traces short.
Program only the necessary bits in any register to minimize clock cycles. RC filtering can also be used to slow the clock edges on the 3 -wire interface, reducing highfrequency spectral content. RC filtering also provides for transient protection against IEC802 testing by shunting high frequencies to ground, while the series resistance attenuates the transients for error-free operation. The same applies to the logic input pins ( $\overline{\mathrm{SHDN}}$, TXGATE, IDLE).

## Complete Dual-Band Quadrature Transmitters

Table 2. Operation Control Register (OPCTRL)

| BIT NAME | POWER-UP STATE | $\begin{gathered} \text { BIT } \\ \text { LOCATION } \\ (0=\text { LSB }) \end{gathered}$ | FUNCTION |
| :---: | :---: | :---: | :---: |
| LO_SEL | 0 | 15 | 0 selects LOL input port; 1 selects LOH port. |
| RCP_TURBO1 | 0 | 14 | Works in conjunction with RCP_TURBO2 (CONFIG register) to set the turbocharge pump mode. (See Table 7) |
| ICP_MAX | 0 | 13 | 1 keeps IF turbo-mode current active even when frequency acquisition is achieved. This mode is used when high operating IF charge-pump current is needed. |
| MODE | 01 | 12, 11 | Sets operating mode according to the following: <br> $00=\mathrm{FM}$ mode <br> $01=$ Cellular digital mode, RFL is selected <br> $10=$ Lower half-band PCS mode, RFH1 is selected <br> 11 = Upper half-band PCS, RFH0 is selected |
| IF_SEL | 0 | 10 | 1 selects IFINH and IFOUTH; 0 selects IFINL and IFOUTL. For FM mode (MODE = 00), set IF_SEL to 0 . |
| VCO_SEL | 0 | 9 | 1 selects high-band IF VCO; 0 selects low-band IF VCO. |
| IFG | 100 | 8, 7, 6 | 3-Bit IF gain Control. Alters IF gain by approximately 2dB per LSB ( 0 to 14dB). Provides a means for adjusting balance between RF and IF gain for optimized linearity. |
| SIDE_BAND | 0 | 5 | When this bit is 1, the upper sideband is selected (LO below RF). When this bit is 0 , the lower sideband is selected (LO above RF). |
| BUF_EN | 0 | 4 | 0 turns IFLO buffer off; 1 turns IFLO buffer on. |
| MOD_TYPE | 1 | 3 | 0 selects direct VCO modulation. (IF VCO is externally modulated and the I/Q modulator is bypassed); 1 selects quadrature modulation. |
| $\overline{\text { STBY }}$ | 1 | 2 | 0 shuts down everything except registers and serial interface. |
| $\overline{\text { TXSTBY }}$ | 1 | 1 | 0 shuts down modulator and upconverter, leaving PLLs locked and registers active. This is the programmable equivalent to the TXGATE pin. |
| SHDN_BIT | 1 | 0 | 0 shuts down everything except serial interface, and also retains all register settings. |

## Complete Dual-Band Quadrature Transmitters

Table 3. Configuration Register (CONFIG)

| BIT NAME | POWER-UP <br> STATE | BIT <br> LOCATION <br> $(0=$ LSB $)$ | FUNCTION |
| :---: | :---: | :---: | :--- |
| IF_PLL_SHDN | 1 | 15 | 0 shuts down the IF PLL. This mode is used with an external IF PLL. |
| RF_PLL_ <br> SHDN | 1 | 14 | 0 shuts down the RF PLL. This mode is used with an external RF PLL. |

## Complete Dual-Band Quadrature Transmitters

Table 4. Current Control Register (ICCCTRL)

| BIT NAME | POWER- <br> UP STATE | BIT <br> LOCATION <br> $(\mathbf{0}=$ LSB) | FUNCTION |
| :--- | :---: | :---: | :--- |
| RESERVED | 00 | 15,14 | Must be set to 00 for normal operation. |
| PSS | 0 | 13 | Prescaler speed select. 0 selects the lower frequency band RFPLL <br> prescaler. 1 selects the higher frequency band prescaler. |
| RESERVED | 0 | 12 | Must be set to 0 for normal operation. |
| MPL | 0 | 11 | Sets the maximum output power level. 0 selects +6.5dBm, 1 selects <br> +10 dBm output power modes. |
| TEMP_COMP | 00 | 10,9 | Sets current scale factor to compensate temperature variations. Set to 10 <br> for best linearity over temperature. |
| RESERVED | 0 | 8 | Must be set to 0 for normal operation. |
| MOD_BYPASS | 0 | 7 | 1 routes differential signal at pins 30 and 31 directly to the IF VGA and <br> bypasses the IF modulator. This mode is used with external modulator. |
| THROTTLE_BACK | 011 | $6,5,4$ | Throttle back rate (Table 6) |
| I_MULT | 1000 | $3,2,1,0$ | Sets current scale factor for PA drivers (Table 5) |

Table 5. Current Scale Factors Set By I_MULT Bits

| BIT NAME | BITS | CURRENT <br> SCALE |
| :---: | :---: | :---: |
|  | 0000 | 0.50 |
|  | 0001 | 0.56 |
|  | 0010 | 0.62 |
|  | 0011 | 0.69 |
|  | 0100 | 0.75 |
|  | 0101 | 0.81 |
|  | 0110 | 0.88 |
|  | 0111 | 0.94 |
|  | 1000 (default) | 1.00 |
|  | 1001 | 1.13 |
|  | 1010 | 1.25 |
|  | 1011 | 1.38 |
|  | 1100 | 1.50 |
|  | 1101 | 1.63 |
|  | 1110 | 1.75 |
|  | 1111 | 1.88 |

Table 6. Throttle-Back Rate Set By THROTTLE_BACK Bits

| BIT NAME | BITS | RATE | UNIT |
| :---: | :---: | :---: | :---: |
| THROTTLE_BACK | 000 | 1.3 |  |
|  | 001 | 1.2 |  |
|  | 010 | 1.1 |  |
|  | 011 (default) | 1.0 |  |
|  | 100 | 0.9 |  |
|  | 101 | 0.8 |  |
|  | 110 | 0.7 |  |
|  | 111 | 0.6 |  |

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Table 7. RF Turbo Charge-Pump Current Setting

| RCP_TURBO1 | RCP_TURBO2 |  |
| :---: | :---: | :--- |
| 0 | 0 | No turbo current. Charge-pump current is set by RCP bits. |
| 0 | 1 | Turbo current turns on every time RFPLL is reprogrammed. Turbo current is <br> automatically turned off after RFPLL is locked. |
| 1 | 0 | Turbo current is always on. |
| 1 | 1 | Turbo current is turned on every time RFPLL is out of lock. |

## Table 8. Power-Down Modes

| POWER-DOWN MODE | COMMENTS |  |  | Ј | O O U | 吕 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| SHDN Pin | Ultra-low shutdown current | X | X | X | X | X |
| $\overline{\text { IDLE Pin }}$ | RX only mode | X | X |  | X | X |
| TXGATE Pin | For punctured TX mode | X | X |  |  |  |
| RF PLL SHDN | For external RF PLL use |  |  | X |  |  |
| IF PLL SHDN | For external IF PLL use |  |  |  |  | X |
| $\overline{\text { TXSTBY Bit }}$ | TX is OFF, but IF and RF LOs stay locked | X | X |  |  |  |

$X=O f f$

## Complete Dual－Band Quadrature Transmitters

Table 9．Register and Control Pin States for Key Operating Modes

|  |  | OPCTRL REGISTER |  |  |  |  |  |  |  | CONFIG REGISTER |  | CONTROL PINS |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| MODE | DESCRIPTION | $\begin{aligned} & \dot{\mu} \\ & 0 \\ & 0 \\ & 0 \end{aligned}$ | $\begin{aligned} & \text { 山 } \\ & \text { O } \\ & \text { O} \end{aligned}$ | $\begin{aligned} & \underline{山} \\ & \boldsymbol{\omega} \\ & \underline{u} \end{aligned}$ | $\begin{aligned} & \text { ü } \\ & \text { O } \\ & 0 \\ & 0 \\ & \hline \end{aligned}$ |  | \|旁 |  |  |  |  | \|ِّهِ |  | ｜ |
| PCS High | PCS upper half－band，RFH0 selected | 1 | 11 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | H | H | H |
| PCS Low | PCS lower half－band，RFH1 selected | 1 | 10 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | 1 | H | H | H |
| Cellular Digital | RFL selected | 0 | 01 | 0 | 0 | 1 | 1 | 1 | 1 | 1 | 1 | H | H | H |
| FM | Direct VCO modulation，RFL selected | 0 | 00 | 0 | 0 | 0 | 1 | 1 | 1 | 1 | 1 | H | H | H |
| PCS Idle | Listen for pages RX ON，TX OFF | 1 | 1X | 1 | 1 | 1 | 1 | X | 1 | X | 1 | L | H | H |
| Cellular Idle | Listen for pages RX ON，TX OFF | 0 | OX | 0 | 0 | X | 1 | X | 1 | X | 1 | L | H | H |
| PCS TXGATE | Gated transmission，PCS | 1 | 1X | 1 | 1 | 1 | 1 | X | 1 | 1 | 1 | H | L | H |
| Cellular TXGATE | Gated transmission，cellular digital | 0 | 01 | 0 | 0 | 1 | 1 | X | 1 | 1 | 1 | H | L | H |
| Sleep | Ultra－Low Current | X | XX | X | X | X | X | X | X | X | X | X | X | L |

$X=$ Don＇t care

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Figure 2. MAX2361 Typical Application Circuit

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Figure 3. MAX2363 Typical Application Circuit

Complete Dual-Band Quadrature Transmitters


Figure 4. MAX2365 Typical Application Circuit
$\qquad$

## Complete Dual-Band Quadrature Transmitters



Figure 5. 3-Wire Interface Diagram

High-frequency bypass capacitors are required close to the pins with a dedicated via to ground. The 48-pin QFN-EP package provides minimal inductance ground by using an exposed paddle under the part. Provide at least five low-inductance vias under the paddle to ground, to minimize ground inductance. Use a solid ground plane wherever possible. Any cutout in the ground plane may act as slot radiator and reduce its shield effectiveness.

Keep the RF LO traces as short as possible to reduce LO radiation and susceptibility to interference.

IF Tank Design
The low-band tank (TANKL+, TANKL-) and high-band tank (TANKH+, TANKH-) are fully differential. The external tank components are shown in Figure 6. The frequency of oscillation is determined by the following equation:

$$
\begin{aligned}
& \text { fosc }=\frac{1}{2 \pi \sqrt{\left(\mathrm{C}_{\text {INT }}+\mathrm{C}_{\text {CENT }}+\mathrm{C}_{\text {VAR }}+\mathrm{C}_{\text {PAR }}\right) \mathrm{L}}} \\
& \mathrm{C}_{\text {VAR }}=\frac{\mathrm{C}_{\mathrm{D}} \times \mathrm{C}_{\mathrm{C}}}{2\left(\mathrm{C}_{\mathrm{D}}+\mathrm{C}_{\mathrm{C}}\right)}
\end{aligned}
$$

CINT = Internal capacitance of TANK port
$C D=$ Capacitance of varactor
CVAR = Equivalent variable tuning capacitance
CPAR = Parasitic capacitance due to PC board pads and traces
CCENT = External capacitor for centering oscillation frequency
$\mathrm{C} C=$ External coupling capacitor to the varactor
Table 10 shows possible component values for various oscillation frequencies.

Internal to the IC, the charge pump will have a leakage of less than 10 nA . This is equivalent to a $300 \mathrm{M} \Omega$ shunt


Figure 6. Tank Port Oscillator
resistor. The charge-pump output must see an extremely high DC resistance of greater than $300 \mathrm{M} \Omega$. This minimizes charge-pump spurs at the comparison frequency. Make sure there is no solder flux under the varactor or loop filter.

Layout Issues
The MAX2361/MAX2363/MAX2365 EV kit can be used as a starting point for layout. For best performance, take into consideration power-supply issues as well as the RF, LO, and IF layout.

## Power-Supply Layout

To minimize coupling between different sections of the IC, the ideal power-supply layout is a star configuration, which has a large decoupling capacitor at a central VCC node. The VCC traces branch out from this node, each going to a separate VCC node in the MAX2361/ MAX2363/MAX2365 circuit. At the end of each trace is a bypass capacitor with impedance to ground less than $1 \Omega$ at the frequency of interest. This arrangement pro-

## Complete Dual-Band Quadrature Transmitters

Table 10. Suggested Component Values for the IF Oscillators

|  | OSC. FREQ. (MHz) | L ( nH ) | Ccent (pF) | $\mathrm{C}_{\mathrm{c}}(\mathrm{pF})$ | CD |
| :---: | :---: | :---: | :---: | :---: | :---: |
| TANKL | 260.76 | 39 | 2.4 | 18 | SMV1763-079 |
|  | 400.0 | 30 | 3.3 | 18 | SMV1763-079 |
|  | 457.2 | 18 | 3.0 | 18 | SMV1763-079 |
| TANKH | 330.0 | 22 | 4.3 | 12 | SMV1763-079 |
|  | 527.2 | 15 | 2.7 | 12 | SMV1763-079 |
|  | 760.0 | 11 | 1.2 | 9 | SMV1763-079 |

## Table 11. Cascaded TDMA Performance

(From I/Q input to PA driver output, IQ_LEVEL $=0, \mathrm{~V}_{\mathrm{I}_{-}}=\mathrm{V}_{\mathrm{Q}}=104 \mathrm{~m} \mathrm{~V}_{\mathrm{RMS}}$, IS136 NADC modulation or $415 \mathrm{mV} \mathrm{V}_{\mathrm{P} \text { - }}$ differential with $0.1 \%$ 3dB peak-average ratio.)

| PARAMETER | CONDITION | VALUE | UNITS |
| :---: | :---: | :---: | :---: |
| IFL Frequency | IF_SEL = 0 | 228.6 | MHz |
| IFH Frequency | IF_SEL = 1 | 263.6 | MHz |
| RFL Frequency Range |  | 824-849 | MHz |
| RFH0 Frequency Range |  | 1850-1910 | MHz |
| LOL Frequency Range |  | 1052.6-1077.6 | MHz |
| LOH Frequency Range |  | 2113.6-2173.6 | MHz |
| LO Input Level | LOL or LOH | -7 | dBm |
| RFL Output Power | $\mathrm{VGC}=2.4 \mathrm{~V}, \mathrm{MPL}=0$ | +7 | dBm |
|  | $\mathrm{V}_{\mathrm{GC}}=2.4 \mathrm{~V}, \mathrm{MPL}=1$ | +10 |  |
| RFH0 Output Power | $\mathrm{V}_{\mathrm{GC}}=2.4 \mathrm{~V}, \mathrm{MPL}=0$ | +6 | dBm |
|  | $\mathrm{VGC}=2.4 \mathrm{~V}, \mathrm{MPL}=1$ | +10 |  |
| Adjacent Channel Power Ratio | foffset $= \pm 30 \mathrm{kHz}$ in 25 kHz BW | -33 | dBc |
| Alternate Channel Power Ratio | foffset $= \pm 60 \mathrm{kHz}$ in 25 kHz BW | -52 | dBc |
| Receive Band Noise Power | $\mathrm{MPL}=0, \mathrm{P}_{\mathrm{RFH}}=+6 \mathrm{dBm}, \mathrm{fRFH}=1910 \mathrm{MHz}$, measured at 1930MHz | -134 | $\mathrm{dBm} / \mathrm{Hz}$ |
|  | $\mathrm{MPL}=1, \mathrm{PRFH0}=+10 \mathrm{dBm}, \mathrm{f}_{\mathrm{RFH}}=1910 \mathrm{MHz}$, measured at 1930MHz | -131 |  |
|  | $\mathrm{MPL}=0, \mathrm{PRFL}=+7 \mathrm{dBm}, \mathrm{fRFL}=849 \mathrm{MHz}$, measured at 869 MHz | -134 |  |
|  | $\mathrm{MPL}=1, \mathrm{PRFL}=+10 \mathrm{dBm}, \mathrm{fRFL}=849 \mathrm{MHz}$, measured at 869 MHz | -131 |  |

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## Table 12. Cascaded WCDMA Performance.

(From I/Q input to PA driver output, IQ_LEVEL $=1, V_{I_{-}}=V_{Q_{-}}=146 \mathrm{mV}$ RMS, uplink 3GPP modulation or 600 mVp -p differential with $0.1 \% 3.25 \mathrm{~dB}$ peak-average ratio.)

| PARAMETER | CONDITIONS | VALUE | UNITS |
| :---: | :---: | :---: | :---: |
| Intermediate Frequency | IF_SEL = 1 | 380 | MHz |
| RFH0 Frequency Range |  | 1920-1980 | MHz |
| LOH Frequency Range |  | 2300-2360 | MHz |
| LO Input Level | LOH | -7 | dBm |
| Maximum RFH0 Output Power | $\mathrm{VGC}=2.4 \mathrm{~V}, \mathrm{MPL}=1$ | 8 | dBm |
| Minimum RFH0 Output Power | ZERO_BIAS $=1, \mathrm{SNR}=20 \mathrm{~dB}$ | -75 | dBm |
| Zero Bias Gain Step | From ZERO_BIAS $=1$ to ZERO_BIAS $=0, \mathrm{~V}$ GC $=2.0 \mathrm{~V}$ | 27 | dB |
| Adjacent Channel Power Ratio | foFFSET $= \pm 3.5 \mathrm{MHz}$ in 30 kHz BW | -60 | dBc |
|  | fOFFSET $= \pm 5 \mathrm{MHz}$ in 3.84 MHz BW | -45 |  |
|  | foFFSET $= \pm 10 \mathrm{MHz}$ in 3.84 MHz BW | -58 |  |
| Receive Band Noise Power | $\mathrm{MPL}=1, \mathrm{P}_{\mathrm{RFH}} 0=+8 \mathrm{dBm}, \mathrm{f} \mathrm{fFH} 0=1950 \mathrm{MHz}$, measured at 2140 MHz | -134 | $\mathrm{dBm} / \mathrm{Hz}$ |

vides local decoupling at each VCc pin. Use at least one via per bypass capacitor for a low-inductance ground connection. Also, connect the exposed paddle to PC board GND with multiple vias to provide the lowest inductance possible.

Matching Network Layout The layout of a matching network can be very sensitive to parasitic circuit elements. To minimize parasitic inductance, keep all traces short and place components as close to the IC as possible. To minimize parasitic capacitance, a cutout in the ground plane (and
any other planes) below the matching network components can be used.
On the high-impedance ports (e.g., IF inputs and outputs), keep traces short to minimize shunt capacitance.

Tank Layout
Keep the traces coming out of the tank short to reduce series inductance and shunt capacitance. Keep the inductor pads and coupling capacitor pads small to minimize stray shunt capacitance.

## Selector Guide

| PART | IF RANGE (MHz) | RF LO RANGE (MHz) | RF RANGE (MHz) |
| :---: | :---: | :---: | :---: |
| MAX2361 | 120 to 235 | 800 to 1150 | 800 to 1000 |
|  | 120 to 380 | 1400 to 2360 | 1700 to 2000 |
| MAX2363 | 120 to 380 | 1400 to 2360 | 1700 to 2000 |
| MAX2365 | 120 to 235 | 800 to 1150 | 800 to 1000 |

## Complete Dual-Band

Quadrature Transmitters


## Complete Dual-Band Quadrature Transmitters

Package Information
(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to www.maxim-ic.com/packages.)


## Complete Dual-Band Quadrature Transmitters

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to www.maxim-ic.com/packages.)

| CIMMDN DIMENSİNS |  |  |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| PKG | 32L 7x7 |  |  | 44L 7x7 |  |  | 48L 7x7 |  |  |
| SYMBDL | MIN. | NDM. | MAX. | MIN. | NDM. | MAX. | MIN. | NDM. | MAX. |
| A | 0.80 | 0.90 | 1.00 | 0.80 | 0.90 | 1.00 | 0.80 | 0.90 | 1.00 |
| A1 | 0.00 | 0.01 | 0.05 | 0.00 | 0.01 | 0.05 | 0.00 | 0.01 | 0.05 |
| A2 | 0.00 | 0.65 | 1.00 | 0.00 | 0.65 | 1.00 | 0.00 | 0.65 | 1.00 |
| A3 | 0.20 REF |  |  | 0.20 REF |  |  | 0.20 REF |  |  |
| b | 0.23 | 0.28 | 0.35 | 0.18 | 0.23 | 0.30 | 0.18 | 0.23 | 0.30 |
| D | 6.90 | 7.00 | 7.10 | 6.90 | 7.00 | 7.10 | 6.90 | 7.00 | 7.10 |
| D1 | 6.75 BSC |  |  | 6.75 BSC |  |  | 6.75 BSC |  |  |
| E | 6.90 | 7.00 | 7.10 | 6.90 | 7.00 | 7.10 | 6.90 | 7.00 | 7.10 |
| E1 | 6.75 BSC |  |  | 6.75 BSC |  |  | 6.75 BSC |  |  |
| e | 0.65 BSC |  |  | 0.50 BSC |  |  | 0.50 BSC |  |  |
| k | 0.25 | - | - | 0.25 | - | - | 0.25 | - | - |
| L | 0.35 | 0.55 | 0.75 | 0.35 | 0.55 | 0.75 | 0.30 | 0.40 | 0.50 |
| N | 32 |  |  | 44 |  |  | 48 |  |  |
| Nd | 8 |  |  | 11 |  |  | 12 |  |  |
| Ne | 8 |  |  | 11 |  |  | 12 |  |  |
| P | 0.00 | 0.42 | 0.60 | 0.00 | 0.42 | 0.60 | 0.00 | 0.42 | 0.60 |
| U | $0{ }^{-}$ |  | 12- | $0{ }^{-}$ |  | $12^{-}$ | $0{ }^{-}$ |  | 12* |


| EXPDSED PAD |  |  |  |  |  | E2 |  |  |
| :--- | :---: | :--- | :--- | :--- | :--- | :--- | :---: | :---: |
| PKG. <br> CIDES | D2 |  |  |  |  |  |  |  |
|  | MIN. | NDM. | MAX. | MIN. | NDM. | MAX. |  |  |
| G3277-2 | 4.55 | 4.70 | 4.85 | 4.55 | 4.70 | 4.85 |  |  |
| G4477-1 | 3.65 | 3.80 | 3.95 | 3.65 | 3.80 | 3.95 |  |  |
| G4477-2 | 4.55 | 4.70 | 4.85 | 4.55 | 4.70 | 4.85 |  |  |
| G4477-3 | 3.15 | 3.30 | 3.45 | 3.15 | 3.30 | 3.45 |  |  |
| G4877-1 | 4.95 | 5.10 | 5.25 | 4.95 | 5.10 | 5.25 |  |  |
| G4877-2 | 5.45 | 5.60 | 5.75 | 5.45 | 5.60 | 5.75 |  |  |

## NOTES:

1. DIE THICKNESS ALLOWABLE IS 0.305 mm MAXIMUM ( .012 INCHES MAXIMUM).
2. DIMENSIONING \& TOLERANCES CONFORM TO ASME Y14.5M. - 1994.
3. $N$ IS THE NUMBER OF TERMINALS.

Nd IS THE NUMBER OF TERMINALS IN $X$-DIRECTION \& Ne IS THE NUMBER OF TERMINALS IN Y-DIRECTION.
4. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.20 AND 0.25 mm FROM TERMINAL TIP.
5. THE PIN \#1 IDENTIFIER MUST EXIST ON THE TOP SURFACE OF THE

PACKAGE BY USING INDENTATION MARK OR INK/LASER MARKED. DETAILS OF PIN * IDENTIFIER IS OPTIONAL, BUT MUST BE LOCATED WITHIN ZONE INDICATED.
6. EXACT Shape and SIze of this feature is optional.
7. ALL DIMENSIONS ARE IN MILLIMETERS.
8. PACKAGE WARPAGE MAX 0.08 mm .
9. APPLIED FOR EXPOSED PAD AND TERMINALS.

EXCLUDE EMBEDDED PART OF EXPOSED PAD FROM MEASURING.
10. MEETS JEDEC MO22O EXCEPT DIMENSION "b" MINIMUM.

亿 APPLY ONLY FOR TERMINAL.
12. this package outline applies to anvil singulation(stepped sides).


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Package Information (continued)
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